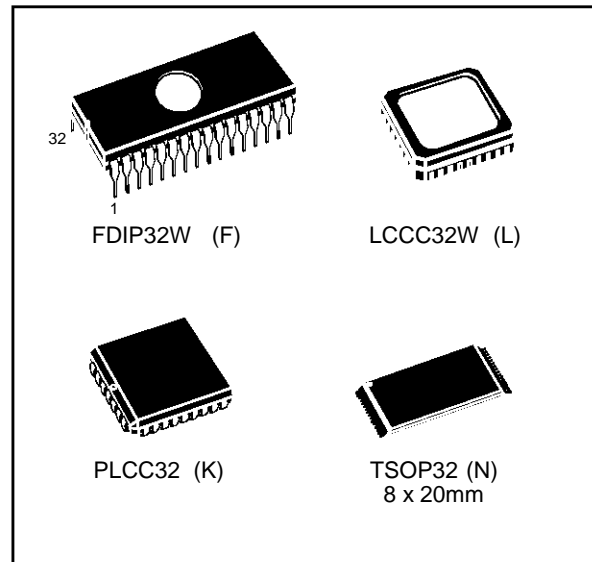


## LOW VOLTAGE 4 Megabit (512K x 8) UV EPROM and OTP EPROM

### DATA BRIEFING

- LOW VOLTAGE READ OPERATION:  
3V to 5.5V
- FAST ACCESS TIME: 120ns
- LOW POWER "CMOS" CONSUMPTION:
  - Active Current 15mA
  - Standby Current 20 $\mu$ A
- PROGRAMMING VOLTAGE: 12.75V
- PROGRAMMING TIMES of AROUND 48sec.  
(PRESTO II ALGORITHM)
- M27V401 is PROGRAMMABLE as M27C4001  
with IDENTICAL SIGNATURE



### DESCRIPTION

The M27V401 is a low voltage, low power 4 Megabit UV erasable and electrically programmable EPROM, ideally suited for handheld and portable microprocessor systems requiring large programs. It is organized as 524,288 by 8 bits.

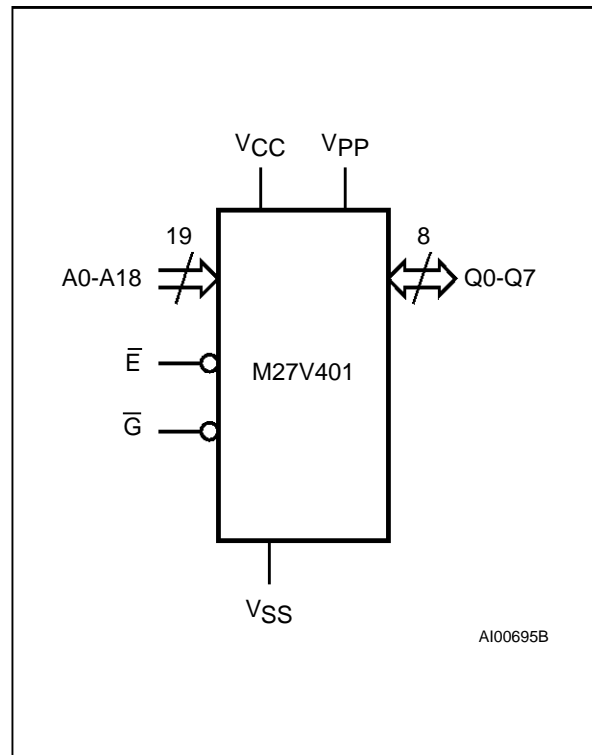
The M27V401 operates in the read mode with a supply voltage as low as 3V. The decrease in operating power allows either a reduction of the size of the battery or an increase in the time between battery recharges.

The M27V401 can also be operated as a standard 4 Megabit EPROM (similar to M27C4001) with a 5V power supply.

### Signal Names

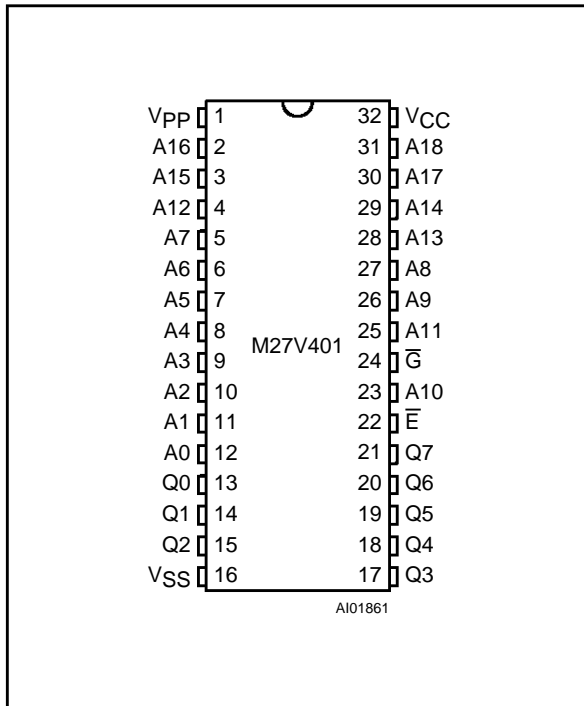
A0 - A18	Address Inputs
Q0 - Q7	Data Outputs
$\bar{E}$	Chip Enable
$\bar{G}$	Output Enable
V <sub>PP</sub>	Program Supply
V <sub>CC</sub>	Supply Voltage
V <sub>SS</sub>	Ground

### Logic Diagram

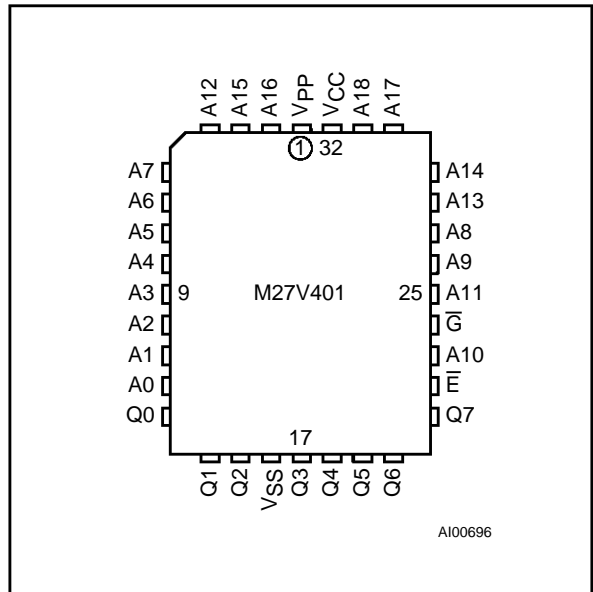


# M27V401

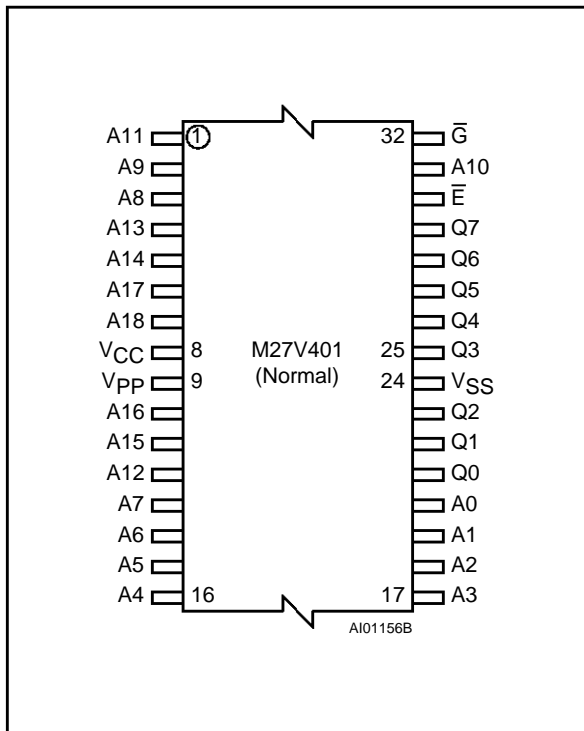
## DIP Pin Connections



## LCC Pin Connections



## TSOP Pin Connections



## Ordering Information Scheme

For a list of available options refer to the current Memory Shortform catalogue.

For further information on any aspect of this device, please contact the SGS-THOMSON Sales Office nearest to you.

Example: M27V401 -120 K 6 TR

<b>Speed</b>	-120	K	6	TR
	-120 120ns			
	-150 150ns			
	-180 180ns			
	-200 200ns			
<b>Package</b>				
	F	FDIP32		
	L	LCCC32W		
	K	PLCC32		
	N	TSOP32		
		8 x 20mm		
<b>Temp. Range</b>				
	1	0 to 70 °C		
	6	-40 to 85 °C		
<b>Option</b>				
	TR	Tape & Reel Packing		